



60V 175°C NPN LOW SAT MEDIUM POWER TRANSISTOR IN POWERDI5060-8

Features

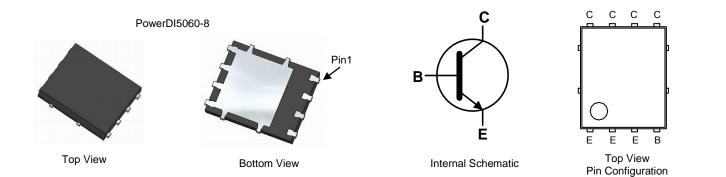
- BV_{CEO} > 60V
- I_C = 3A Continuous Collector Current
- I_{CM} = 8A Peak Pulse Current
- R_{CE(SAT)} <90mΩ
- Rated to +175°C Ideal for High Ambient Temperature Environments
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (DXTN3C60PSQ)

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)

Applications

- Power Management
- Load Switch
- Linear Mode Voltage Regulator
- Backlighting Applications



Ordering Information (Note 4)

Part Number Compliance Marking Reel Size (inches) Tape Width (mm) Qua	antity Dar Deal
	antity Per Reel
DXTN3C60PS-13 AEC-Q101 DXTN3C60PS 13 12	1,000

Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DXTN3 = Product Type Marking Code C60PS = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 19 = 2019) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	60	V
Collector-Emitter Voltage	V _{CEO}	60	V
Emitter-Base Voltage	V _{EBO}	7	V
Base Current	IB	500	mA
Continuous Collector Current	lc	3	A
Peak Pulse Collector Current	I _{CM}	8	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	PD	2.5	W	
Thermal Desistance, lunction to Ambient	(Note 5)	P	60	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R _{0JA}	140		
Thermal Desistance, Junction to Case	(Note 5, 7)	P	2	00000	
Thermal Resistance, Junction to Case	(Note 6, 7)	R _{θJC}	12	°C/W	
Operating and Storage Temperature Range		TJ, T _{STG}	-55 to +175	°C	

ESD Ratings (Note 8)

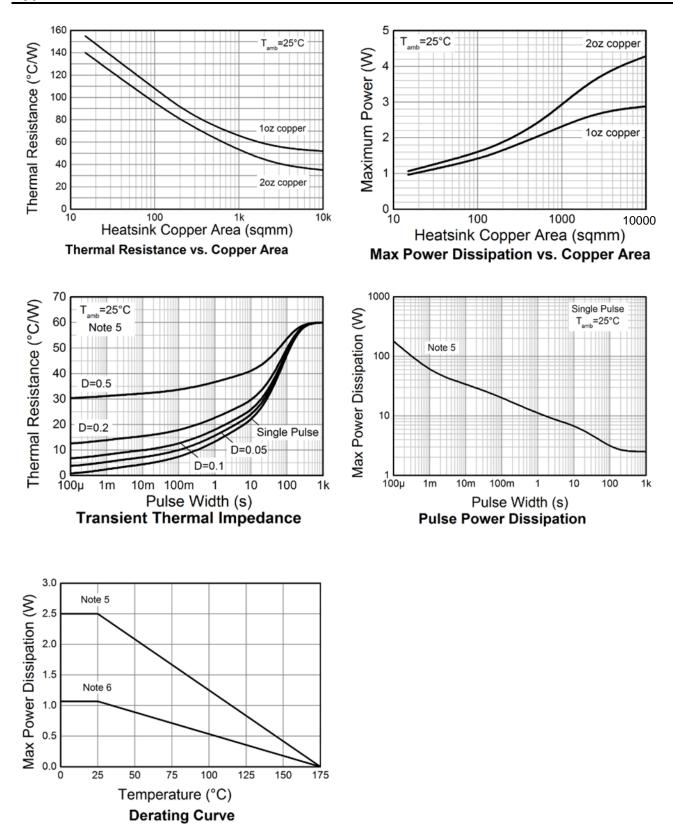
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is Notes:

For a device moduled with the collector lead on 25mm x 25mm x 25mm 202 copper measured under still air conditions whilst operating in a steady-state.
Same as note (5), except mounted on minimum recommended pad layout.
Thermal resistance from junction to the top of the case.
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Typical Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)





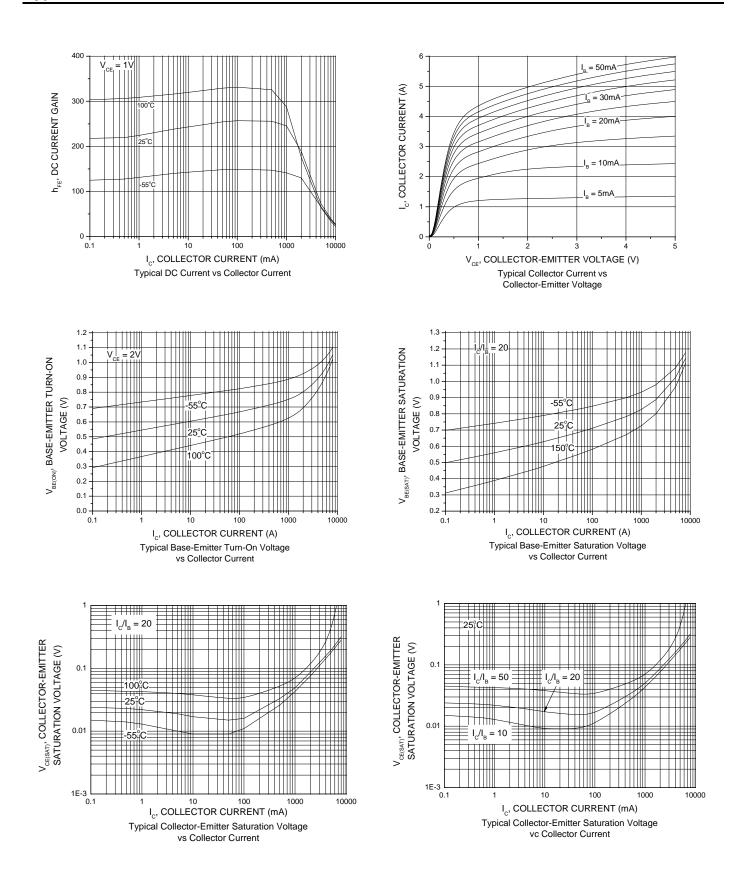
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	60	—	—	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	60	—	—	V	$I_{\rm C} = 10 {\rm mA}$
Emitter-Base Breakdown Voltage	BV _{EBO}	7	_	—	V	I _E = 100μA
Collector-Base Cutoff Current	1	—	_	100	nA	$V_{CB} = 48V$
Collector-Base Cuton Current	I _{CBO}	—	_	50	μA	$V_{CB} = 48V @T_J = +150^{\circ}C$
Emitter Cutoff Current	I _{EBO}	—	_	100	nA	V _{EB} = 7V
Collector-Emitter Cutoff Current	I _{CES}	—	_	100	nA	$V_{CES} = 48V$
ON CHARACTERISTICS (Note 9)					-	
		200	400	—		$I_{C} = 500 \text{mA}, V_{CE} = 2 \text{V}$
DC Current Gain	h _{FE}	200	330	—		$I_C = 1A, V_{CE} = 2V$
DC Current Gain	NFE	100	180	—	_	$I_C = 2A, V_{CE} = 2V$
		50	100	—		$I_C = 3A, V_{CE} = 2V$
Collector-Emitter Saturation Voltage		—	70	120	mV	$I_{C} = 1A, I_{B} = 50mA$
	V _{CE(SAT)}	—	180	270	mV	I _C = 3A, I _B = 300mA
Collector-Emitter Saturation Resistance	R _{CE(SAT)}	_	60	90	mΩ	$I_{\rm C} = 3A, I_{\rm B} = 300 \text{ mA}$
Base-Emitter Saturation Voltage		_	0.86	1.0	v	$I_{C} = 1A, I_{B} = 100mA$
Dase-Emilier Saturation Voltage	V _{BE(SAT)}	_	1.0	1.2	v	$I_{C} = 2A, I_{B} = 200mA$
Base-Emitter Turn-On Voltage	V _{BE(ON)}	—	0.65	0.85	V	$I_C=0.1A,\ V_{CE}=2V$
SMALL SIGNAL CHARACTERISTICS					-	
Current Gain-Bandwidth Product	f⊤		140		MHz	$V_{CE}=10V,I_C=100mA,f=10MHz$
Output Capacitance	Cobo	_	17	—	pF	$V_{CB} = 10V$, f = 1MHz
Delay Time	t _D	_	15	—	ns	
Rise Time	t _R	_	120	_	ns	
Turn-On Time	t _(ON)	—	135	_	ns	V _{CC} = 12.5V, I _C = 1A
Storage Time	t _S	—	800	—	ns	$I_{B1} = -I_{B2} = 0.05A$
Fall Time	t _F	—	300	—	ns	
Turn-Off Time	t _(OFF)	_	1100	—	ns	

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.

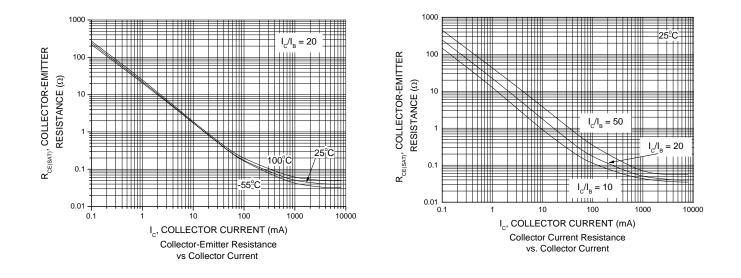


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.) (continued)

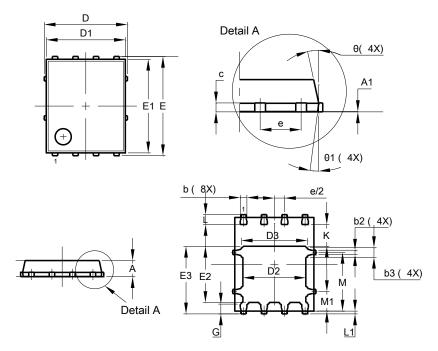




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8

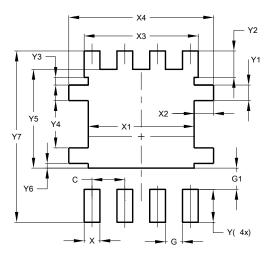


PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	į	5.15 BSC			
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
ш	6.15 BSC				
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
e	1.27 BSC				
G	0.51	0.71	0.61		
K	0.51	-	-		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
Μ	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
θ	10º	12º	11º		
θ1	6°	8º	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI5060-8



Dimensions	Value (in mm)
С	1.270
G	0.660
G1	0.820
Х	0.610
X1	4.100
X2	0.755
X3	4.420
X4	5.610
Y	1.270
Y1	0.600
Y2	1.020
Y3	0.295
Y4	1.825
Y5	3.810
Y6	0.180
Y7	6.610



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